

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	256	((soi or (silicon adj on adj insulator)) near2 (layer\$1 or film\$1)) near5 (thin\$3 and thick\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 17:26
L2	113	1 and (CMOS or (complementary adj metal adj oxide adj transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 17:27
S1	6049	((438/106) or (438/118) or (438/455) or (438/458) or (438/459)).CCLS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 14:14
S2	612	S1 and ((soi or (silicon adj on adj insulator)) near2 (wafer\$1 or substrate\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 17:25
S3	144	S2 and (delaminat\$3 or (smart near cut))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:29
S4	66	S3 and (trench\$2 or cavit\$3 or void\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:43

S5	31	("20040029358" "4179324" "4704302" "4931405" "5034343" "5110748" "5198371" "5234535" "5250446" "5256581" "5310446" "5374564" "5413951" "5494835" "5524339" "5559043" "5567654" "5618739" "5622896" "5633174" "5661333" "5714395" "5804086" "5817368" "5863830" "5863832" "5897331" "5993677" "6020252" "6048411" "6294478").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:21
S6	18	("4179324" "5374564" "5494835" "5494846" "5559043" "5616506" "5695557" "5714395" "5723372" "5854123" "5863830" "5882987" "5993677" "6020252" "6121112" "6156624" "6194245" "6225192").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:25
S7	2924	bond\$3 same ((soi or (silicon adj on adj insulator)) near2 (wafer\$1 or substrate\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:29
S8	325	S7 and (delaminat\$3 or (smart near cut))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:29
S9	170	S8 and (trench\$2 or cavit\$3 or void\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:30
S10	115	S9 not S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:30

S11	33	("20020063285" "4341009" "5343064" "5374564" "5376561" "5473181" "5547886" "5604368" "5631186" "5646058" "5654220" "5656548" "5670387" "5736435" "5741733" "5767001" "5844294" "5882987" "5889293" "5889302" "5891761" "5939745" "5970339" "5998808" "6037617" "6067062" "6096582" "6188122" "6291858" "6384439" "6531754" "6538916" "6548848").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:38
S12	0	("6759282").URPN.	USPAT	OR	OFF	2005/06/10 14:40
S13	31	("20040029358" "4179324" "4704302" "4931405" "5034343" "5110748" "5198371" "5234535" "5250446" "5256581" "5310446" "5374564" "5413951" "5494835" "5524339" "5559043" "5567654" "5618739" "5622896" "5633174" "5661333" "5714395" "5804086" "5817368" "5863830" "5863832" "5897331" "5993677" "6020252" "6048411" "6294478").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:40
S14	7	("4121334" "4894709" "5034343" "5198371" "5374564" "5415727" "5632854").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:41
S15	4906	(trench\$2 or cavit\$3 or void\$1) near2 wafer\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:44
S16	423	S15 and ((soi or (silicon adj on adj insulator)) near2 (wafer\$1 or substrate\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:44

S17	207	S16 and S7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/10 14:45
S18	41	("1258368" "1658669" "3213318" "3609593" "4806815" "5179499" "5184269" "5216273" "5261747" "5309056" "5355712" "5367584" "5441343" "5467068" "5475318" "5483799" "5536988" "5558304" "5600174" "5602955" "5606635" "5629665" "5644177" "5659285" "5722989" "5796152" "5813441" "5862003" "5867302" "5870518" "5881198" "5909078" "5954079" "5994816" "6023121" "6114794" "6236139" "6275320").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 14:58
S19	6	("6386507").URPN.	USPAT	OR	OFF	2005/06/10 15:00
S20	6	("5043773" "5190890" "5314107" "5407856" "5441803" "5964942").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/10 15:02